



NHD-C0220AA-FSW-FTW

Graphic Liquid Crystal Display Module

NHD- Newhaven Display

CO220- COG, 2 Lines x 20 Characters

AA- Model

F- Transflective

SW- Side White LED Backlight

F- FSTN Positive

T- 12:00 Optimum View

W- Wide Temp

RoHS Compliant

Newhaven Display International, Inc.

2661 Galvin Ct. Elgin IL, 60124

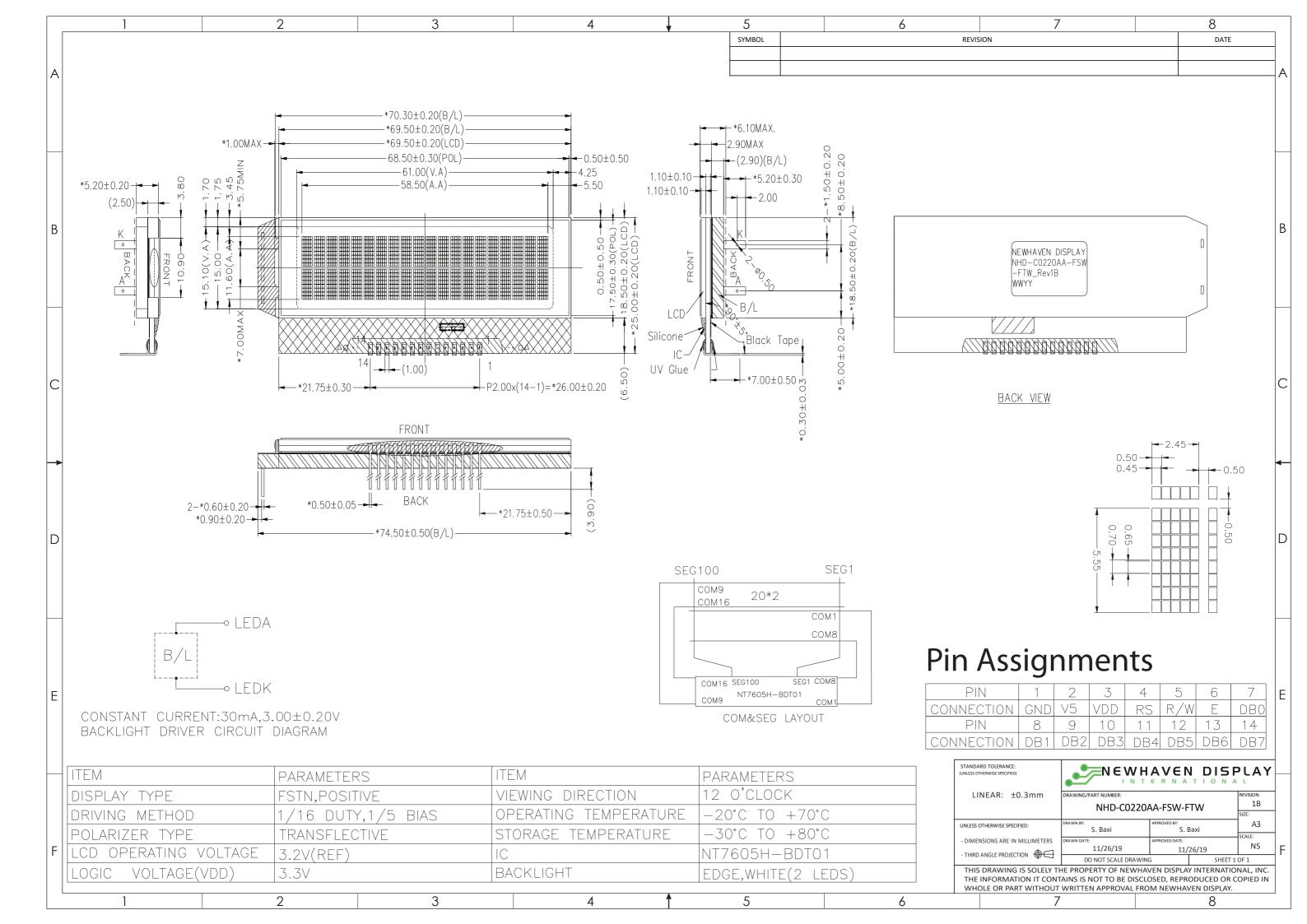
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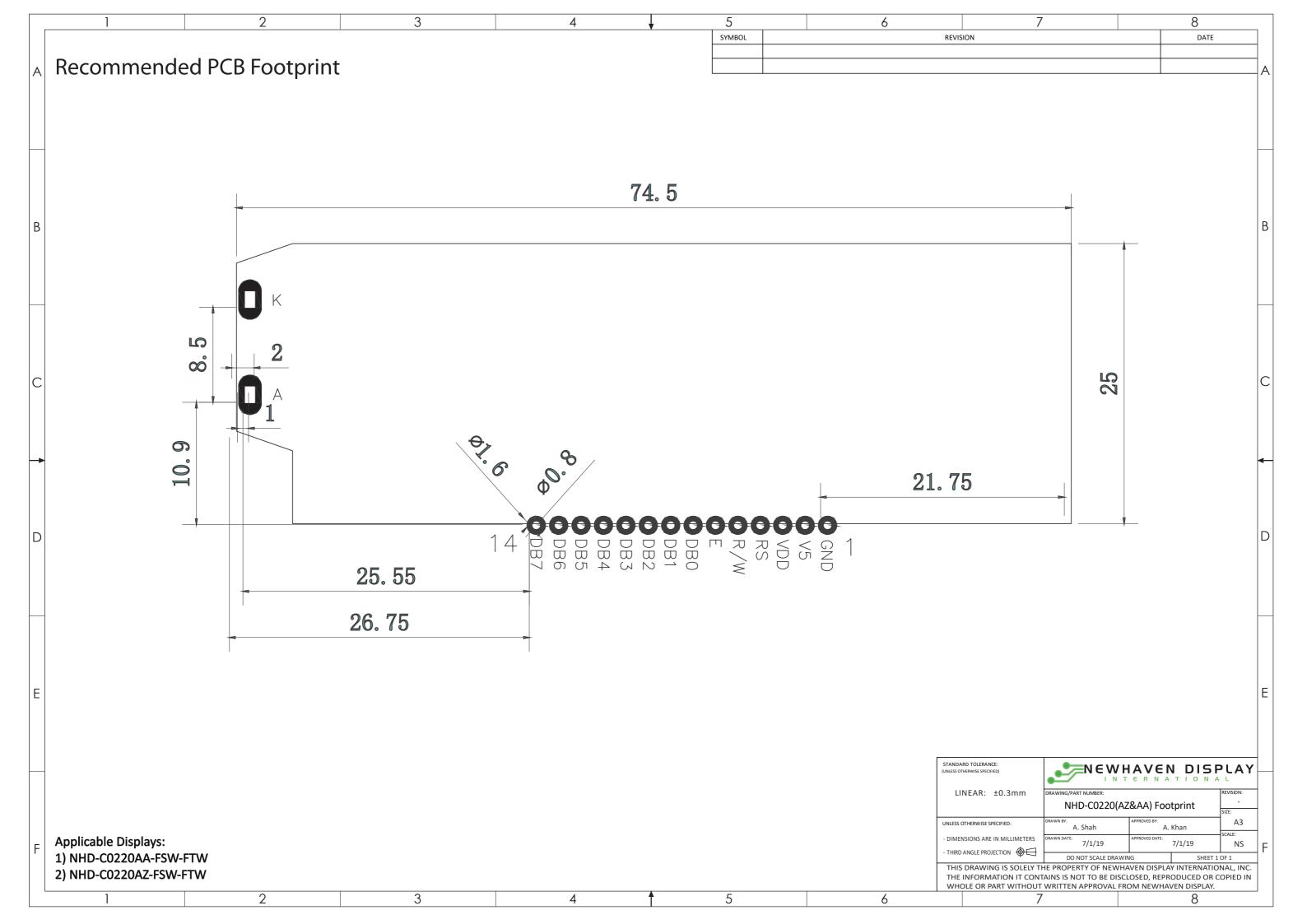
Document Revision History

Revision	Date	Description	Changed by
0	11/5/10	Initial Release	-
1	5/27/11	1 Display character address code updated	
2	6/2/11	Timing characteristics updated	AK
3	9/28/15	Electrical characteristics, response times updated	SB
4	12/28/17	Backlight Characteristics Updated	SB
5	2/19/19	Backlight Current Updated	SB
6	7/5/19	Added PCB Footprint Drawing	AS
7	11/26/19	Electrical Characteristics Updated	SB

Functions and Features

- 2 lines x 20 characters
- Built-in NT7605 controller
- 3.3V power supply
- 1/16 duty, 1/5 bias





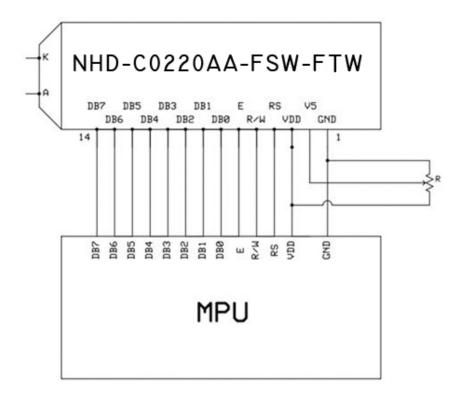
Pin Description and Wiring Diagram

Pin No.	Symbol	External Connection	Function Description
1	GND	Power Supply	Ground
2	V 5	Adj. Power Supply	Supply Voltage for Contrast (approx. 0.1V)
3	V_{DD}	Power Supply	Supply Voltage for LCD and Logic
4	RS	MPU	Register Select: 0=Instruction, 1=Data
5	R/W	MPU	Read / Write select: 0=Write, 1=Read
6	Е	MPU	Operation Enable Signal.
7-10	DB0 – DB3	MPU	Four low order bi-directional three-state data bus lines.
			These four are not used during 4-bit operation.
11-14	DB4 – DB7	MPU	Four high order bi-directional three-state data bus lines.
Α	LED +	Power Supply	Backlight Anode (30 mA @ 3V)
K	LED -	Power Supply	Backlight Cathode (Ground)

Recommended LCD connector: 2.0mm pitch, 14pins Soldered to PCB, or JST p/n: PHR-14

Backlight connector: A and K pins Mates with: Solder to wires or PCB

Recommended Breakout Board: NHD-PCB40



Electrical Characteristics

Item	Symbol	Condition	Min.	Тур.	Max.	Unit
Operating Temperature Range	Top	Absolute Max	-20	25	+70	°C
Storage Temperature Range	T _{ST}	Absolute Max	-30	25	+80	°C
Supply Voltage	V_{DD}	ı	3.0	3.3	3.5	V
Supply Current	I_{DD}	$V_{DD} = 3.3V$	0.3	0.6	2	mA
Supply for LCD (contrast)	$V_{DD} - V_5$	$T_{OP} = 25^{\circ}C$	3.0	3.2	3.5	V
"H" Level input	V_{IH}	-	0.8 * V _{DD}	-	V_{DD}	V
"L" Level input	VIL	-	0	-	0.2 *V _{DD}	V
"H" Level output	Vон	-	V _{DD} - 0.6	-	V_{DD}	V
"L" Level output	Vol	-	GND	-	GND + 0.6	V
Backlight Supply Current	V_{LED}	-	-	30	36	mA
Backlight Supply Voltage	I _{LED}	I _{LED} = 30 mA	2.8	3.0	3.3	V

^{*}The LED of the backlight is driven by current; drive voltage is for reference only. Drive voltage must be selected to ensure backlight current drain is below MAX level stated.

Optical Characteristics

Ite	em	Symbol	Condition	Min.	Тур.	Max.	Unit
	Тор	φΥ+		-	40	-	0
Optimal Viewing	Bottom	φΥ-	CD > 2	-	40	-	0
Angels	Left	θХ-	CR ≥ 2	-	35	-	0
	Right	θХ+		-	35	-	٥
Contrast Ratio		CR	-	-	6	-	-
Response Time (rise)		T _R	-	-	100	160	ms
Response Time (fa	II)	T _F	-	-	150	200	ms

Controller Information

Built-in NT7605H-BDT01 Controller.

Please download specification at http://www.newhavendisplay.com/app notes/NT7605.pdf

NOTE: The Busy Flag of the NT7605 controller may not always be responsive. Add sufficient delays and/or a time-out check routine to continue operation if busy flag is not cleared.

Note: during internal operation, busy flag (DB7) is read "High". Busy flag check must be preceded by the next instruction.

DDRAM Address

	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18	19	20
(00	01	02	03	04	05	06	07	08	09	0A	OB	0C	0D	0E	0F	10	11	12	13
4	10	41	42	43	44	45	46	47	48	49	4A	4B	4C	4D	4E	4F	50	51	52	53

Table of Commands

				INST	RUCT	ION C	ODE					Execution
Instruction	RS	R/W	DB7	DB6	DB5	DB4	DB3	DB2	DB1	DB0	Description	Time (Max) (fosc = 540KHZ)
Clear Display	0	0	0	0	0	0	0	0	0	1	Clear entire display area. Restore display from shift, and load address counter with DDRAM address 00H	1.64ms
Display/ Cursor Home	0	0	0	0	0	0	0	0	1	-	Restore display from shift and load address counter with DDRAM address 00H	1.64ms
Entry mode Set	0	0	0	0	0	0	0	1	I/D	S	Specify direction of cursor movement and display shift mode. This operation takes place after each data transfer (read/write)	40μs
Display ON/ OFF control	0	0	0	0	0	0	1	D	С	В	Set activation of display (D), cursor (C), and Blinking of cursor (B)	40µs
Display/ Cursor	0	0	0	0	0	1	S/C	R/L	-	-	Shift display or move cursor	40µs
Function set	0	0	0	0	1	DL	N	F	-	-	Set interface data length (DL) number of the display line (N), and character font (F)	40µs
RAM Address Set	0	0	0	1		•	AC	CG		•	Set CGRAM address in address counter.	40µs
DDRAM Address Set	0	0	1		I		ADD				Set DDRAM address in address counter.	40µs
Busy Flag/ Address Counter Read	0	1	BF				AC				Read Busy Flag (BF) and contents of Address Counter (AC)	1µs
CGRAM/ DDRAM Data Write	1	0				Write	Data				Write data into internal RAM (DDRAM/CGRAM).	40µs
CGRAM/ DDRAM Data Read	1	1				Read	Data				Read data from internal RAM (DDRAM/CGRAM).	40µs
	I/D = 1 : IncrementI/D = 0 : DecrementS = 1 : Display Shift OnDDRAM : Display Data RamD = 1 : Display OnCGRAM : CharacterC = 1 : Cursor Display OnCGRAM : CharacterB = 1 : Cursor Blink OnGenerator RAMS/C = 1 : Shift DisplayS/C = 0 : Move CursorR/L = 1 : Shift RightR/L = 0 : Shift LeftDL = 1 : 8-BitDL = 0 : 4-BitN = 1 : Dual LineN = 0 : Single LineF = 1 : 5x10 dotsF = 0 : 5x8 dotsBF = 1 : Internal OperationADD : Display Data RAM Address											
	BF =		eady fo structic								AC : Address Counter	

Timing Characteristics

Write from MPU to NT7605

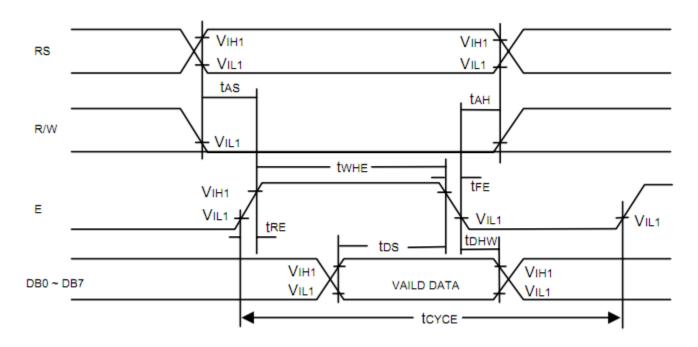


Figure 2. Bus Write Operation Sequence (Writing data from MPU to NT7605)

Write Cycle (VDD = $4.5V\sim5.5V$, GND = 0V, TA = $25^{\circ}C$)

Symbol	Parameter	Min.	Тур.	Max.	Unit	Conditions
tcyce	Enable Cycle Time	500	-	-	ns	Figure 2
twhe	Enable "H" Level Pulse Width	300	-	-	ns	Figure 2
tre, tre	Enable Rise/Fall Time	-	-	25	ns	Figure 2
tas	RS, R/W Setup Time	60 ¹	-	-	ns	Figure 2
IAS	RS, R/W Setup Time	100 ²				
tah	RS, R/W Address Hold Time	10	-	-	ns	Figure 2
tos	Data Output Delay	100	-	-	ns	Figure 2
tDHW	Data Hold Time	10	-	-	ns	Figure 2

Notes: 1: 8-bit operation mode 2: 4-bit operation mode

Read from NT7605 to MPU

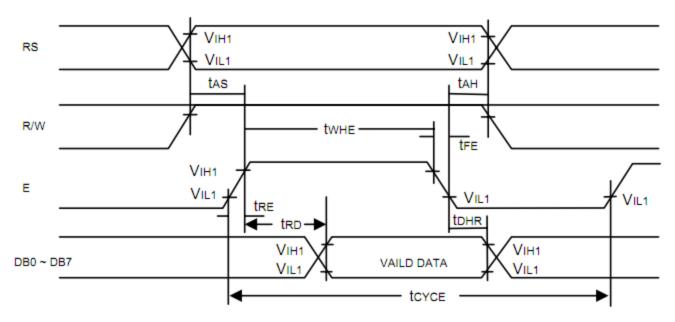


Figure 1. Bus Read Operation Sequence (Reading out data from NT7605 to MPU)

Read Cycle (VDD = $4.5V\sim5.5V$, GND = 0V, TA = $25^{\circ}C$)

Symbol	Parameter	Min.	Тур.	Max.	Unit	Conditions
tcyce	Enable Cycle Time	500	-	-	ns	Figure 1
twhe	Enable "H" Level Pulse Width	300	-	-	ns	Figure 1
tre, tre	Enable Rise/Fall Time	-	-	25	ns	Figure 1
440	DC DAM Setus Time	60 ¹	-	-	no	Figure 1
tas	RS, R/W Setup Time	100 ²			ns	Figure 1
tan	RS, R/W Address Hold Time	10	-	-	ns	Figure 1
trd	Read Data Output Delay	-	-	190	ns	Figure 1
tdhr	Read Data Hold Time	20	-	-	ns	Figure 1

Notes: 1: 8-bit operation mode 2: 4-bit operation mode

Built-in Font Table

					High	er 4-bit	(D4 to I	D7) of 0	haracte	er Code	/Mayar	facimal					
L		0	1	2	3	4	5	6	7	8	9	A	В	С	D	E	F
	0	CG RAM (1)			0	9	-	•	Ė.					9	Ħ,		p
	1	CG RAM (2)			1			.	-			:::	7	Ŧ	<u></u> ,	ä	
	2	CG RAM (3)		**	2		R	b	r				1	ij	×	P	
	n	CG RAM (4)		#	S		5	C	Ü				ņ	Ŧ	₩	€.	:::
	4	CG RAM (5)		\$	4	D	T	d	₺				I	ŀ	†:	H	<u> </u>
	15	CG RAM (6)		7.	5		U.	₩	L.I			::	7	; †		S	ü
	6	CG RAM (7)		8.	6	F	Ų	₩.	V			ij	Ħ			p	Σ
(exadecimal)	7	CG RAM (B)		ä	7	8	W	9	W			.;;	#	X		9	Л
acter Code (i	8	CG RAM (1)		€	8	H	Χ	h	×			4	.7	#		.,"	×
bit (D0 to D3) of Character Code (Hexadecimal)	۵	CG RAM (2)		Þ	9	I	Y	i	'			•	Ť	ļ	ı.	:	Ш
चं	A	CG RAM (3)		*	::	"	Z	ij	Z			::::		ľ	ŀ	j	#
Lower	В	CG RAM (4)		- 	;	K	I.	k	:			; †	ÿ			×	Ħ
	O	CG RAM (5)		;:	<	<u></u>	¥	1				†7	٠	7		4	
	D	CG RAM (6)			::::	M		m	•			.:1.	Z	^,	<u></u> .,	₩.	
	Е	CG RAM (7)			>	N	۰۰.	m					Œ	:†:	···	ñ	
	F	CG RAM (8)			?				÷				기	₹	:: :	Ö	

Example Initialization Program

'INIT		
A = &H30		
Call Writecom	'wake	up
Waitms 100		
Call Writecom	'wake	up
Waitms 10		
Call Writecom	'wake	up
Waitms 10		
A = &H38		
'function set		
Call Writecom		
A = &H10		
'shift display=no		
Call Writecom		
A = &HOC		
'display on		
Call Writecom		
A = &H06		
'entry mode set		
Call Writecom		
·		
Sub Writecom		
P1 = A		
Reset P3.0		
'instruction		
Reset P3.7		
'RW		
Waitms 1		
Set P3.4		
'E		
Waitms 1		
Reset P3.4	' E	3
End Sub		
·		
Sub Writedata		
P1 = A		
Set P3.0		
'data		
Reset P3.7		
'RW		
Waitms 1		
Set P3.4		
'E		
Waitms 1		
Reset P3.4	' E	C
End Sub		

Quality Information

Test Item	Content of Test	Test Condition	Note
High Temperature storage	Endurance test applying the high storage temperature for a long time.	+80°C , 120 Hrs.	2
Low Temperature storage	Endurance test applying the low storage temperature for a long time.	-30°C , 120 Hrs.	1,2
High Temperature Operation	Endurance test applying the electric stress (voltage & current) and the high thermal stress for a long time.	+70°C, 120 Hrs.	2
Low Temperature Operation	Endurance test applying the electric stress (voltage & current) and the low thermal stress for a long time.	-20°C , 120 Hrs.	1,2
High Temperature / Humidity Operation	Endurance test applying the electric stress (voltage & current) and the high thermal with high humidity stress for a long time.	+40°C, 90% RH, 120 Hrs.	1,2
Thermal Shock resistance	Endurance test applying the electric stress (voltage & current) during a cycle of low and high thermal stress.	-20°C,30min -> 25°C,5min -> 70°C,30min = 1 cycle 10 cycles	
Vibration test	Endurance test applying vibration to simulate transportation and use.	10-55Hz , 15mm amplitude. 60 sec in each of 3 directions X,Y,Z For 15 minutes	3
Static electricity test	Endurance test applying electric static discharge.	Air Discharge= ±8kV, Contact Discharge = ±4kV Five Times	

Note 1: No condensation to be observed.

Note 2: Conducted after 4 hours of storage at 25°C, 0%RH.

Note 3: Test performed on product itself, not inside a container.

Precautions for using LCDs/LCMs

See Precautions at www.newhavendisplay.com/specs/precautions.pdf

Warranty Information and Terms & Conditions

http://www.newhavendisplay.com/index.php?main_page=terms